

DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOC莫斯 HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOC莫斯 HE4000B Logic Package Outlines/Information HEF, HEC

HEF40106B **gates** **Hex inverting Schmitt trigger**

Product specification
File under Integrated Circuits, IC04

January 1995

Hex inverting Schmitt trigger**HEF40106B
gates****DESCRIPTION**

Each circuit of the HEF40106B functions as an inverter with Schmitt-trigger action. The Schmitt-trigger switches at different points for the positive and negative-going input signals. The difference between the positive-going voltage (V_P) and the negative-going voltage (V_N) is defined as hysteresis voltage (V_H).

This device may be used for enhanced noise immunity or to "square up" slowly changing waveforms.

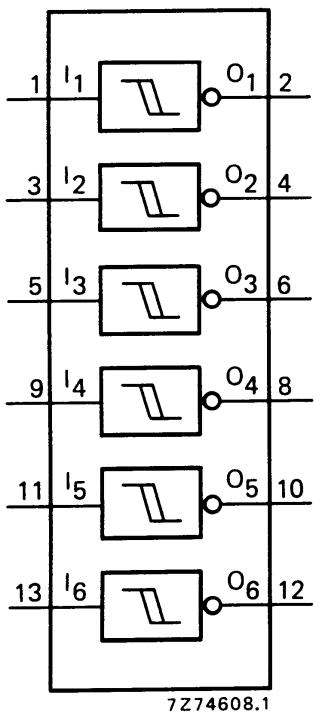


Fig.1 Functional diagram.

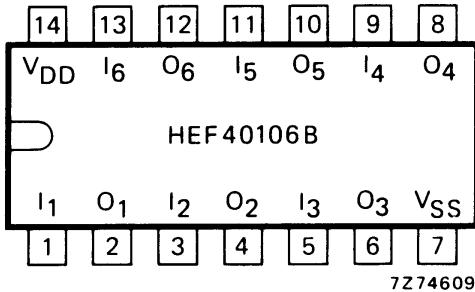


Fig.2 Pinning diagram.

- HEF40106BP(N): 14-lead DIL; plastic (SOT27-1)
- HEF40106BD(F): 14-lead DIL; ceramic (cerdip) (SOT73)
- HEF40106BT(D): 14-lead SO; plastic (SOT108-1)
- (): Package Designator North America

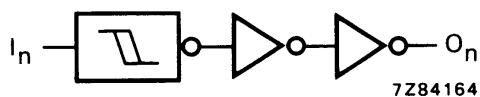


Fig.3 Logic diagram (one inverter).

FAMILY DATA, I_{DD} LIMITS category GATES

See Family Specifications

Hex inverting Schmitt trigger

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DC CHARACTERISTICS

 $V_{SS} = 0 \text{ V}$; $T_{amb} = 25 \text{ }^{\circ}\text{C}$

	V_{DD} V	SYMBOL	MIN.	TYP.	MAX.
Hysteresis voltage	5	V_H	0,5	0,8	V
	10		0,7	1,3	V
	15		0,9	1,8	V
Switching levels positive-going input voltage	5	V_P	2	3,0	3,5 V
	10		3,7	5,8	7 V
	15		4,9	8,3	11 V
negative-going input voltage	5	V_N	1,5	2,2	3 V
	10		3	4,5	6,3 V
	15		4	6,5	10,1 V

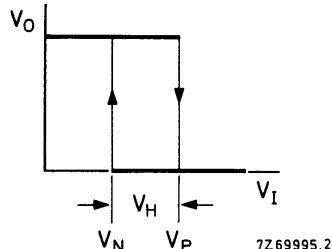
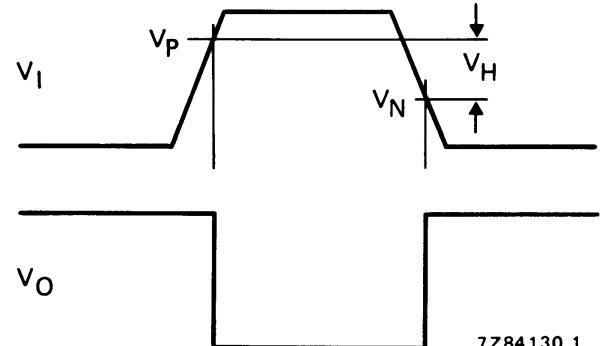


Fig.4 Transfer characteristic.

Fig.5 Waveforms showing definition of V_P , V_N and V_H , where V_N and V_P are between limits of 30% and 70%.

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gates**AC CHARACTERISTICS** $V_{SS} = 0 \text{ V}$; $T_{amb} = 25^\circ\text{C}$; $C_L = 50 \text{ pF}$; input transition times $\leq 20 \text{ ns}$

	V_{DD} V	SYMBOL	TYP.	MAX.	TYPICAL EXTRAPOLATION FORMULA
Propagation delays $I_n \rightarrow O_n$ HIGH to LOW	5	t_{PHL}	90	180	ns
	10		35	70	ns
	15		30	60	ns
	5	t_{PLH}	75	150	ns
	10		35	70	ns
	15		30	60	ns
	5	t_{THL}	60	120	ns
	10		30	60	ns
	15		20	40	ns
Output transition times HIGH to LOW	5	t_{TLH}	60	120	ns
	10		30	60	ns
	15		20	40	ns
	5		10	120	ns
	10		9	60	ns
	15		6	40	ns

	V_{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power dissipation per package (P)	5 10 15	$2\ 300 f_i + \sum (f_o C_L) \times V_{DD}^2$ $9\ 000 f_i + \sum (f_o C_L) \times V_{DD}^2$ $20\ 000 f_i + \sum (f_o C_L) \times V_{DD}^2$	where f_i = input freq. (MHz) f_o = output freq. (MHz) C_L = load capacitance (pF) $\sum (f_o C_L)$ = sum of outputs V_{DD} = supply voltage (V)

Hex inverting Schmitt trigger

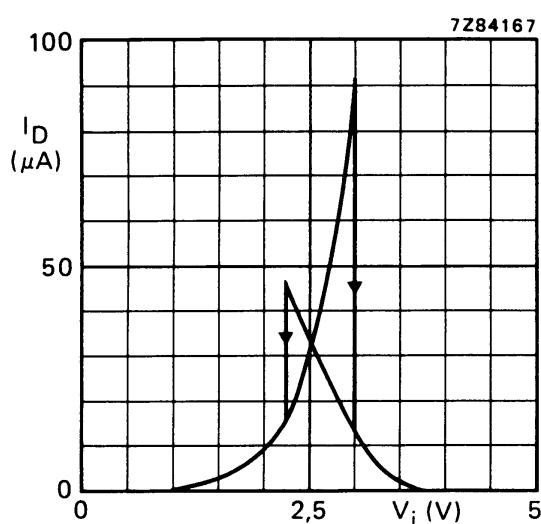
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Fig.6 Typical drain current as a function of input voltage; $V_{DD} = 5$ V; $T_{amb} = 25$ °C.

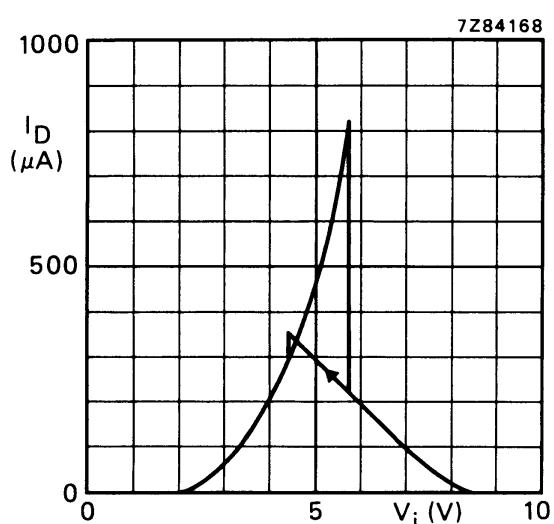


Fig.7 Typical drain current as a function of input voltage; $V_{DD} = 10$ V; $T_{amb} = 25$ °C.

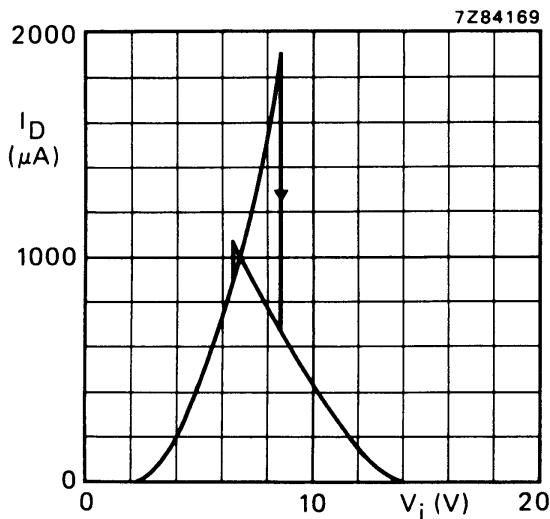
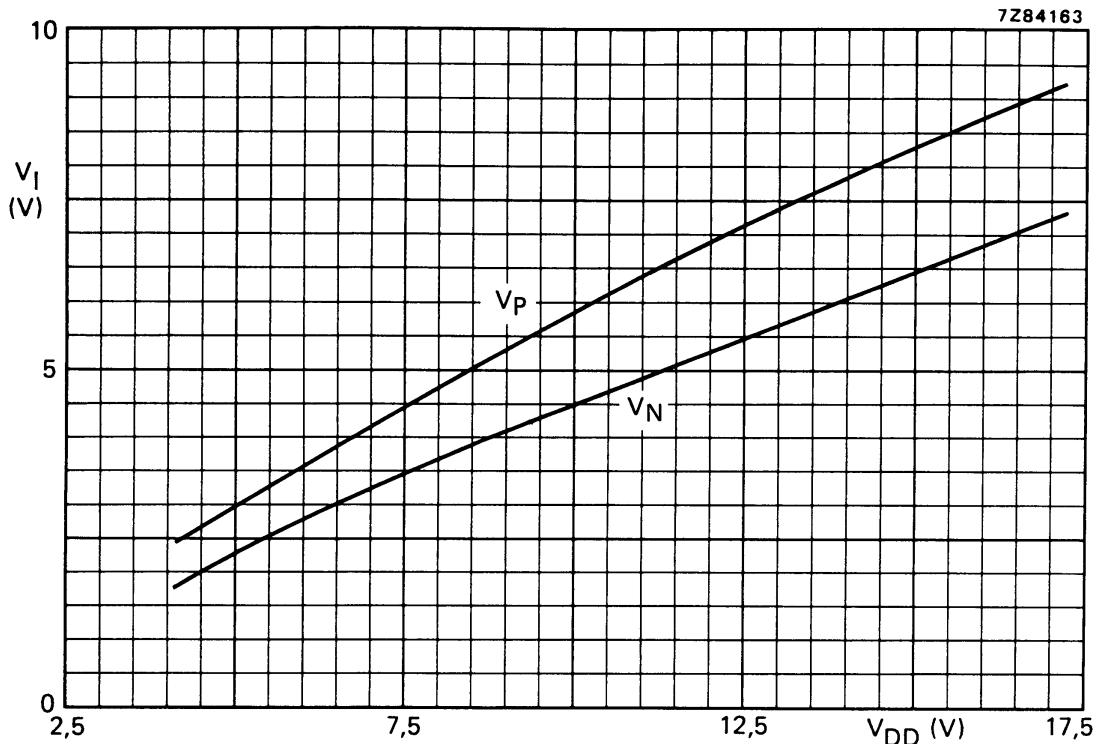
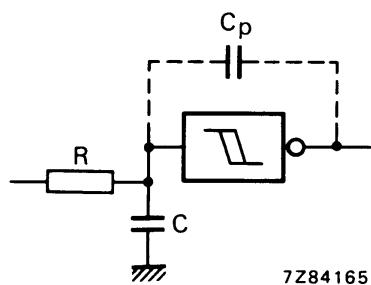


Fig.8 Typical drain current as a function of input voltage; $V_{DD} = 15$ V; $T_{amb} = 25$ °C.

Hex inverting Schmitt trigger

HEF40106B
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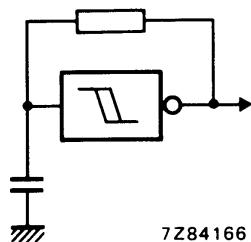
If a Schmitt trigger is driven via a high impedance ($R > 1 \text{ k}\Omega$) then it is necessary to incorporate a capacitor C of such value that: $\frac{C}{C_p} > \frac{V_{DD} - V_{SS}}{V_H}$, otherwise oscillation can occur on the edges of a pulse.

C_p is the external parasitic capacitance between input and output; the value depends on the circuit board layout.

Hex inverting Schmitt trigger**HEF40106B
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Some examples of applications for the HEF40106B are:

- Wave and pulse shapers
- Astable multivibrators
- Monostable multivibrators.



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Fig.11 The HEF40106B used as an astable multivibrator.

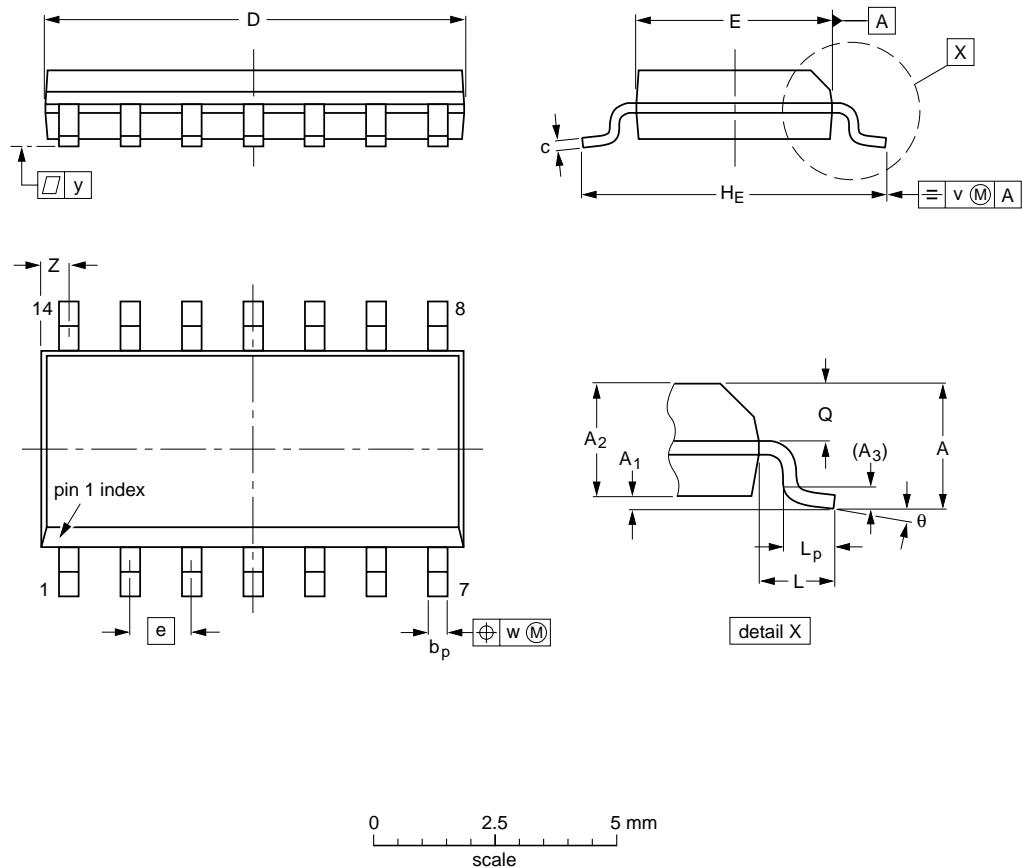
Package information

Package outlines

SO

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	z ⁽¹⁾	θ
mm	1.75 0.10	0.25 1.45	0.25 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069 0.004	0.010 0.049	0.057 0.049	0.01	0.019 0.014	0.0100 0.0075	0.35 0.34	0.16 0.15	0.050	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT108-1	076E06S	MS-012AB				95-01-23 97-05-22

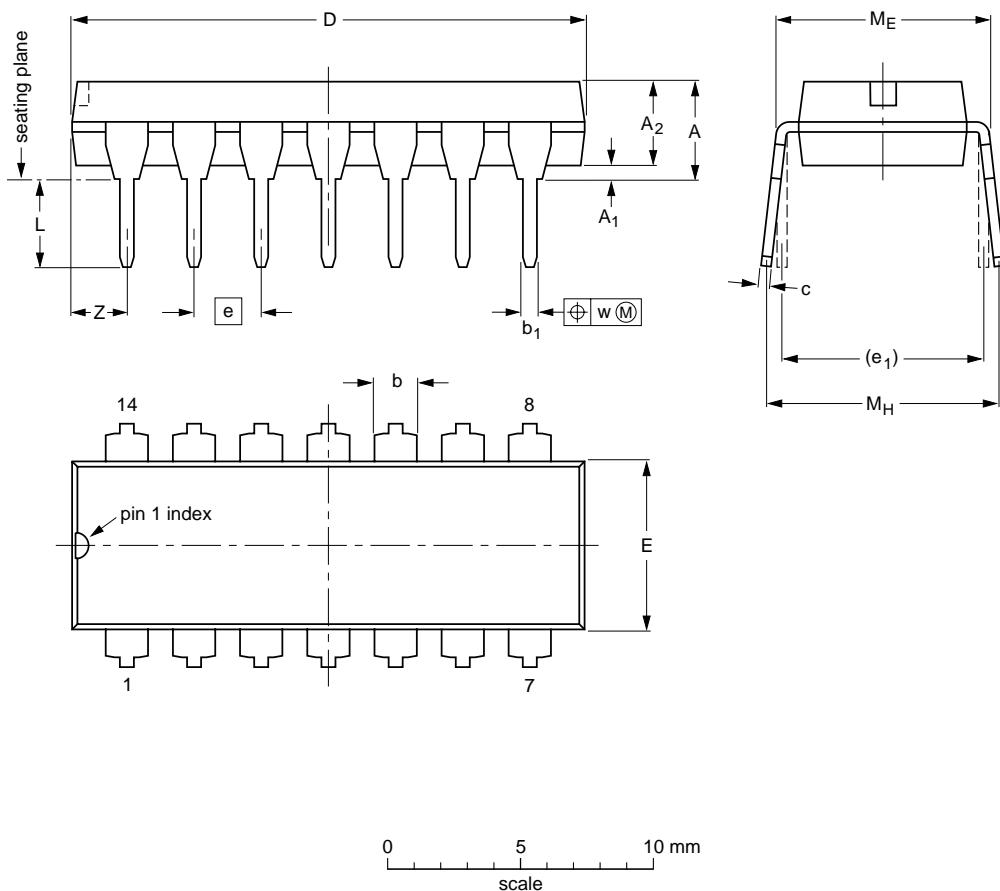
Package information

Package outlines

DIP

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.13	0.53 0.38	0.36 0.23	19.50 18.55	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.2
inches	0.17	0.020	0.13	0.068 0.044	0.021 0.015	0.014 0.009	0.77 0.73	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.087

Note

- Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT27-1	050G04	MO-001AA				92-11-17 95-03-11